MMIC SURFACE MOUNT

Monolithic Amplifier

RAM-4+

50Ω DC to 1 GHz

FEATURES

- Wideband, DC to 1 GHz
- Cascadable Ceramic Package
- Internally Matched to 50Ω
- Low Noise Figure, 6.5 dB Typ.
- Excellent Repeatability
- Aqueous Washable
- Protected Under US Patent 6,943,629

Generic photo used for illustration purposes only

CASE STYLE: AF190

+RoHS Compliant
The +Suffix identifies RoHS Compliance.
See our website for methodologies and qualifications

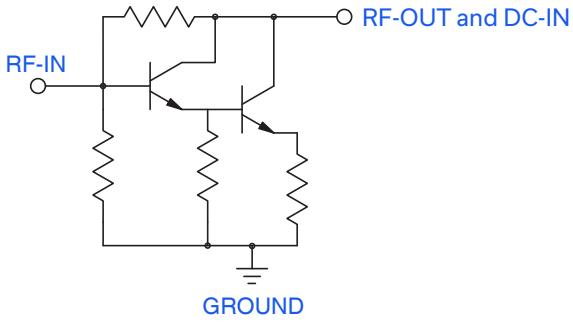
APPLICATIONS

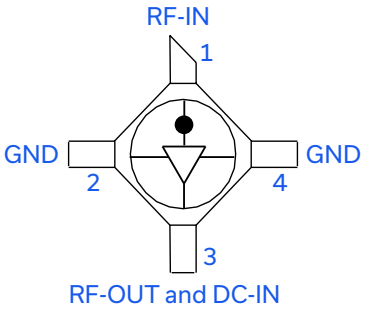
- Cellular
- UHF/VHF
- Communication Systems
- Transmission Receivers

PRODUCT OVERVIEW

RAM-4+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in a ceramic surface-mount package. RAM-4+ uses Darlington configuration and is fabricated using InGaP HBT technology. Expected MTBF is 300 years at +100°C case temperature.

SIMPLIFIED SCHEMATIC AND PIN DESCRIPTION





Function	Pin Number	Description
RF-IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.

REV. E
ECO-024944
RAM-4+
MCL NY
250320

Monolithic Amplifier

RAM-4+

50Ω DC to 1 GHz

ELECTRICAL SPECIFICATIONS AT +25°C AND 50 mA UNLESS NOTED OTHERWISE

Parameter	Conditions (GHz)	Min.	Typ.	Max.	Units
Frequency Range[1]		DC		1	GHz
Gain	0.1 1	 7.0[2]	8.5 8.0		dB
Input Return Loss	DC - 1		15.5		dB
Output Return Loss	DC - 1		10		dB
Output Power @ 1 dB Compression	1		+12.5		dBm
Output IP3	1		+25.5		dBm
Noise Figure	1		6.5		dB
Recommended Device Operating Current			50		mA
Device Operating Voltage			+5.25		V
Device Voltage Variation vs. Temperature at 50 mA			-2.2		mV/°C
Device Voltage Variation vs. Current at +25°C			23.0		mV/mA
Thermal Resistance, Junction-to-Case[3]			140		°C/W

1. Guaranteed specification DC-1 GHz. Low frequency cut off determined by external coupling capacitors.
2. Full temperature range.
3. Case is defined as ground leads.

ABSOLUTE MAXIMUM RATINGS

Parameter	Ratings
Operating Temperature	-54°C to +100°C
Storage Temperature	-65°C to +150°C
Operating Current	100 mA
Power Dissipation	540 mW
Input Power	+13 dBm

Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.

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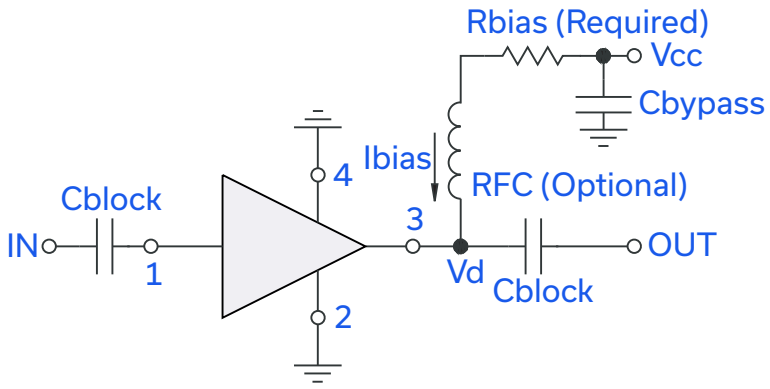
RAM-4+

50Ω DC to 1 GHz

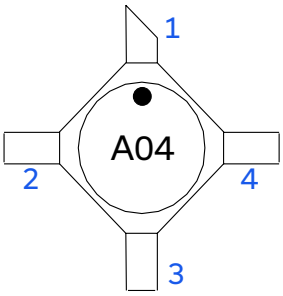
RECOMMENDED APPLICATION CIRCUIT



Test Board includes case, connectors, and components (in bold) soldered to PCB

R BIAS	
Vcc	"1%" Res. Values (Ohms) for Optimum Biasing
7	34.8
8	54.9
9	75
10	95.3
11	115
12	133
13	154
14	174
15	196

PRODUCT MARKING



Markings in addition to model number designation may appear for internal quality control purposes.

Monolithic Amplifier

RAM-4+

50Ω DC to 1 GHz

ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASHBOARD. CLICK HERE

Performance Data & Graphs	Data Table Swept Graphs S-Parameter Data Set (.zip file)
Case Style	AF190 Ceramic surface-mount, 0.083 body diameter
Suggested Layout for PCB Design	PL-254
Evaluation Board	TB-414-4+
Environmental Ratings	ENV08T6

ESD RATING

Human Body Model (HBM): Class 1B (500 V to < 1,000 V) in accordance with ANSI/ESD STM 5.1 - 2001
Machine Model (MM): Class M1 (< 100 V) in accordance with ESD STM 5.2 - 1999

NOTES

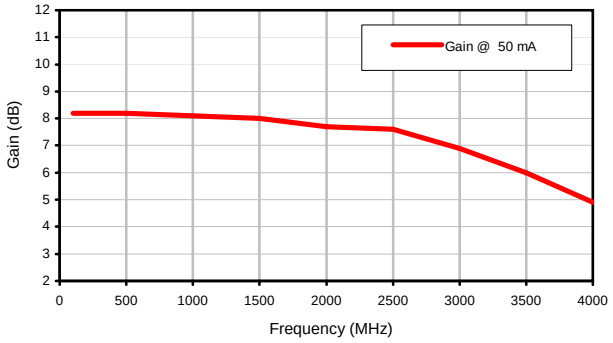
A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuits' applicable established test performance criteria and measurement instructions.
C. The parts covered by this specification document are subject to Mini-Circuits' standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/terms/viewterm.html

Typical Performance Data

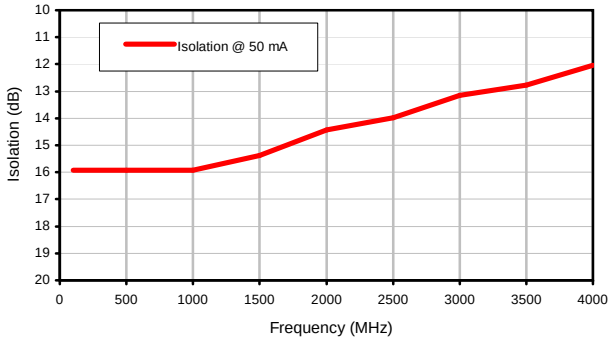
FREQUENCY (MHz)	GAIN (dB) 50 mA	ISOLATION (dB) 50 mA	RETURN LOSS IN (dB) 50 mA	RETURN LOSS OUT (dB) 50 mA
100	8.20	15.92	14.42	20.00
500	8.20	15.92	14.89	17.72
1000	8.10	15.92	15.39	14.89
1500	8.00	15.39	15.39	12.40
2000	7.70	14.42	14.42	11.06
2500	7.60	13.98	12.40	9.37
3000	6.90	13.15	10.17	9.12
3500	6.00	12.77	8.18	8.64
4000	4.90	12.04	6.74	8.40

Typical Performance Curves

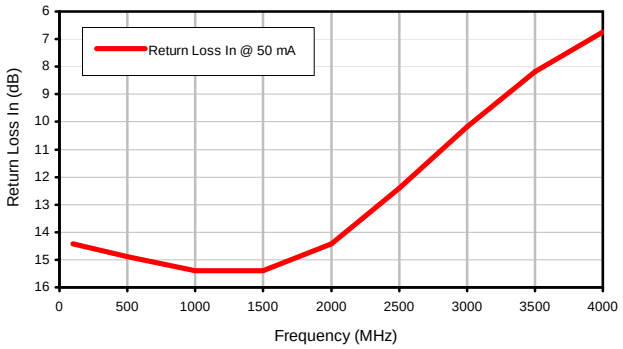
Gain



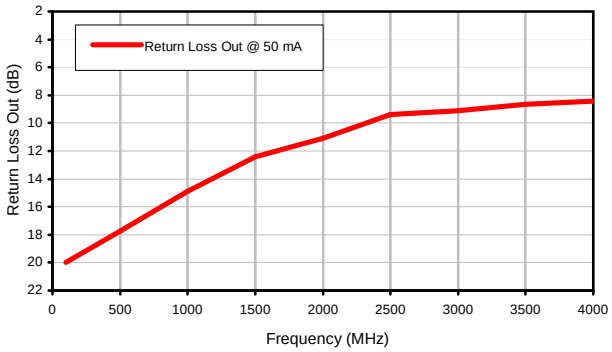
ISOLATION



Return Loss In



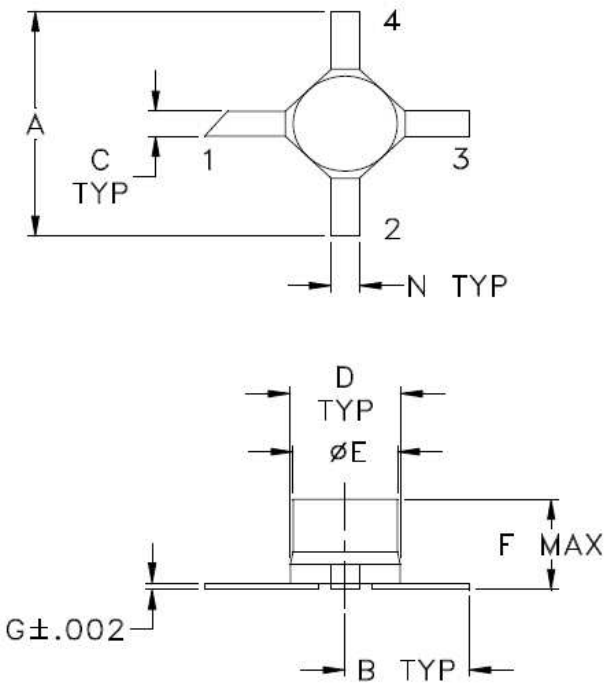
Return Loss Out



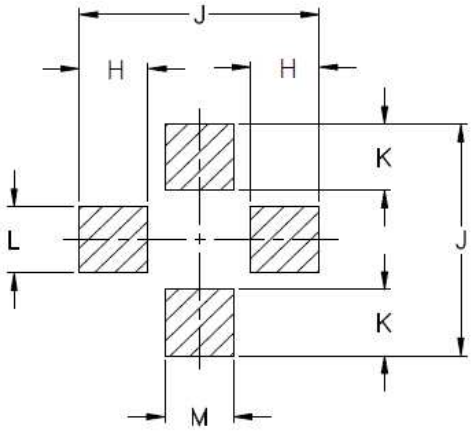
Case Style AF

Outline Dimensions

AF190



PCB Land Pattern



Suggested Layout,
Tolerance to be within ±.002

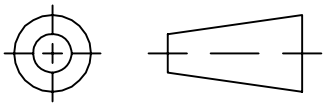
CASE #	A	B	C	D	E	F	G	H	J	K	L	M	N	WT. GRAM
AF190	.180 (4.57)	.090 (2.29)	.020 (0.51)	.100 (2.54)	.083 (2.11)	.072 (1.83)	.005 (0.13)	.060 (1.52)	.210 (5.33)	.060 (1.52)	.040 (1.02)	.040 (1.02)	.020 (0.51)	.04

Dimensions are in inches (mm). Tolerances: 2Pl. ± .03; 3Pl. ± .015

Notes:

1. Case material: Ceramic.
2. Termination material:
   Nickel-Iron alloy 42.
3. Termination finish:
   For RoHS Case Styles: Tin-Silver alloy plate over Nickel barrier or Matte-Tin Plate or Matte-Tin Plate over Nickel barrier. See PCN# PCN20-035
   For RoHS-5 Case Styles: Tin-Lead plate or Tin-Lead Plate over Nickel barrier. See PCN# PCN20-035
4. Termination (1):
   Identified by diagonally cut lead.
5. Special Tolerances: Termination width ± .005 inch, termination thickness ± .002 inch, cap diameter ± .005 inch.

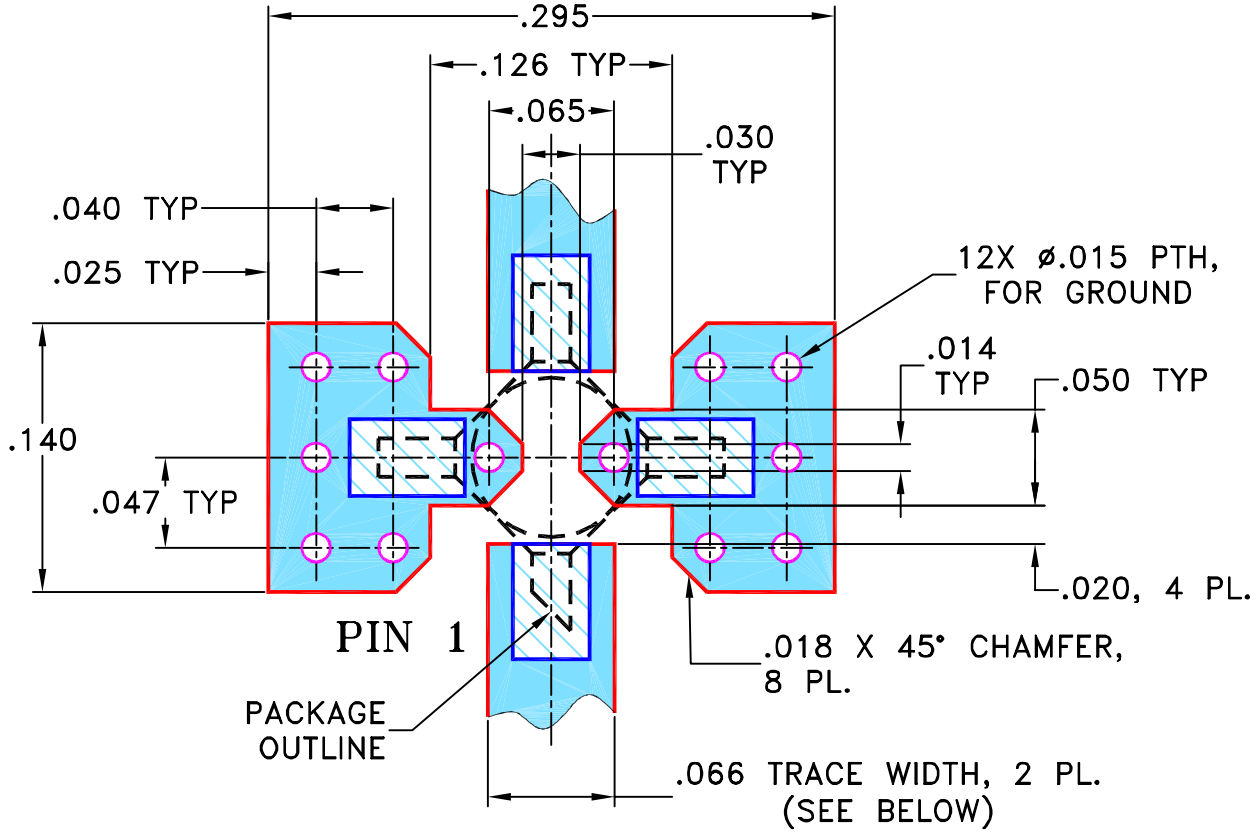
THIRD ANGLE PROJECTION



REVISIONS

REV	ECN No.	DESCRIPTION	DATE	DR	AUTH
OR	M108436	NEW RELEASE	11/14/06	PW	IG
A	M108585	UPDATED DRAWING PER TB-414+	11/24/06	PW	MM

SUGGESTED MOUNTING CONFIGURATION FOR AF190 CASE STYLE, "cb" PIN CONNECTION



NOTES:

1. TRACE WIDTH IS SHOWN FOR ROGERS RO4350B WITH DIELECTRIC THICKNESS .030" ± .002"; COPPER: 1/2 OZ. EACH SIDE. FOR OTHER MATERIALS TRACE WIDTH MAY NEED TO BE MODIFIED.
2. BOTTOM SIDE OF THE PCB IS CONTINUOUS GROUND PLANE.
3. IF PCB DESIGN RULES ALLOW, PLACE GROUND VIAS UNDER THE LAND PATTERN FOR BETTER RF PERFORMANCE. OTHERWISE PLACE GROUND VIAS AS CLOSE TO LAND PATTERN AS POSSIBLE.

DENOTES PCB COPPER LAYOUT WITH SMOBC (SOLDER MASK OVER BARE COPPER)

DENOTES COPPER LAND PATTERN FREE OF SOLDER MASK

UNLESS OTHERWISE SPECIFIED		INITIALS	DATE
DIMENSIONS ARE IN INCHES	DRAWN	PW	11/11/06
TOLERANCES ON:	CHECKED	IL	11/14/06
2 PL DECIMALS ±	APPROVED	IG	11/14/06
3 PL DECIMALS ± .005			
ANGLES ±			
FRACTIONS ±			

Mini-Circuits®

ASHEETA1.DWG REV:A DATE:01/12/95

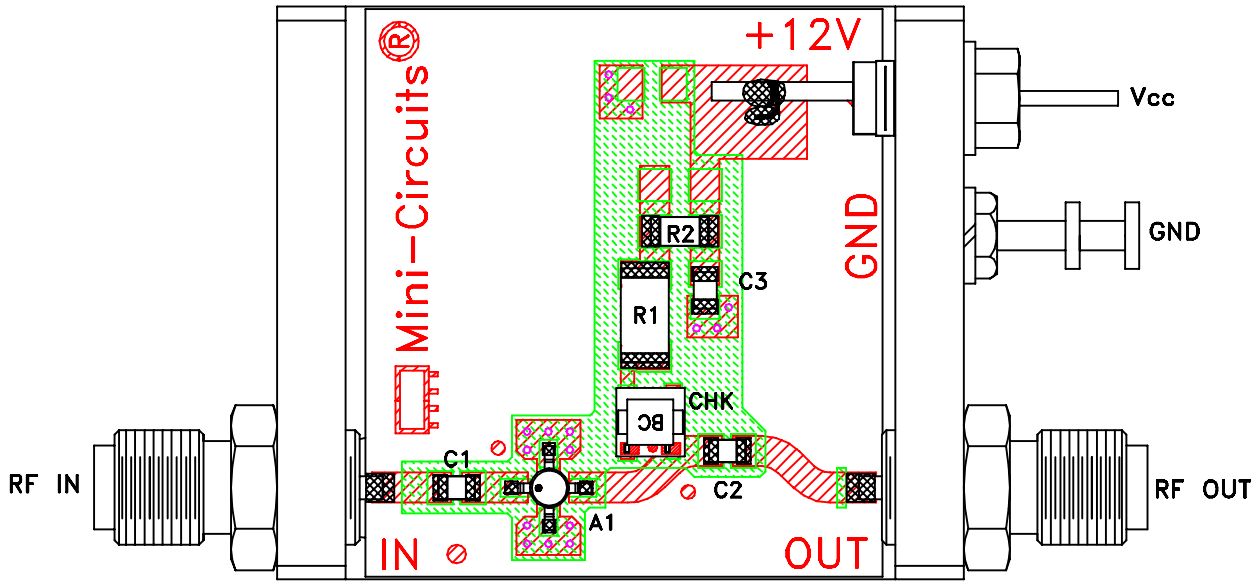
Mini-Circuits® 13 Neptune Avenue Brooklyn NY 11235

PL, cb, AF190, RAM, TB-414-X+

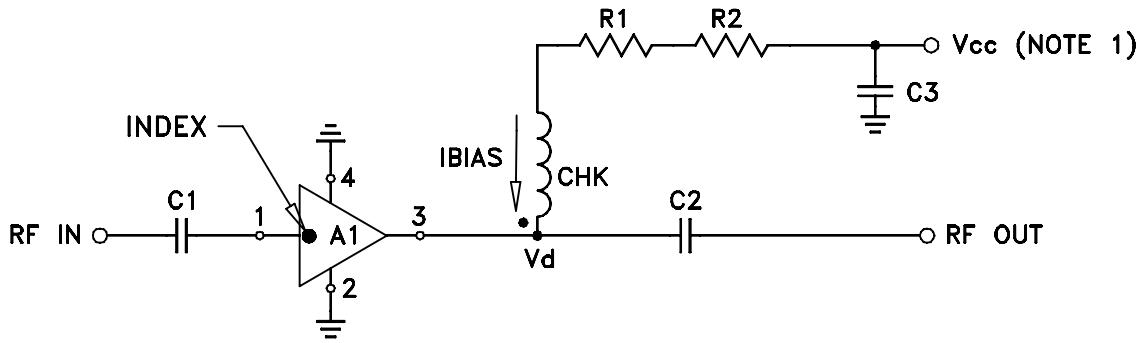
SIZE	CODE IDENT	DRAWING NO:	REV:
A	15542	98-PL-254	A

FILE:	SCALE:	SHEET:
98PL254	10:1	1 OF 1

Evaluation Board and Circuit



TB-414-4+



COMPONENT	VALUE
A1	RAM-4(+)
C1 (NOTE 4)	2400 pF
C2 (NOTE 4)	2400 pF
C3 (bypass)	0.1 uF
R1	133 Ohms, 0.75W
R2	2.21 Ohms, 0.25W
CHK	Mini-Circuits TCCH-80+

Schematic Diagram

NOTE:

1. Vcc voltage: +12±0.2V.
2. SMA Female connectors.
3. PCB material: Rogers RO4350 or equivalent, dielectric constant=3.5, dielectric thickness=.030 inch.
4. Capacitors, C1 & C2 should be free of resonance up to the highest frequency specified.

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Environmental Specifications ENV47

All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
Operating Temperature	-54° to 100°C Ambient Environment	Individual Model Data Sheet
Storage Temperature	-65° to 150° C Ambient Environment	Individual Model Data Sheet
HTOL	1000 hours at 125°C	MIL-STD-883, Method 1005, Condition B
Thermal Shock	-55° to 105°C, 100 cycles	MIL-STD-202, Method 107, Condition A-3, except +100°C
Mechanical Shock	1500g, 0.5 ms, 5 shock pulses, Y1 direction only	MIL-STD-883, Method 2002, Condition B, except Y1 direction only.
Vibration (Variable Frequency)	50g peak 20-2000 Hz, 4 times in each of three perpendicular directions (total 12)	MIL-STD-883, Method 2007, Condition B
Autoclave	15 psig, 100% RH, 121°C, 96 hours	JEDEC-STD-22-B, Method A102
Solderability	10X Magnification	J-STD-002, Para 4.2.5, Test S, 95% Coverage
Solder Reflow Heat	Sn-Pb Eutetic Process: 240°C peak Pb-Free Process: 260°C peak	J-STD-020, Table 4-1, 4-2 and 5-2; Figure 5-1
Moisture Sensitivity: Level 1	Bake at 125°C for 24 hours. Soak at 85°C/85%RH for 168 hours Reflow 3 cycles at 260°C peak	J-STD-020
Marking Resistance to Solvents	Isopropyl alcohol + mineral spirits at 25°C; terpene defluxer at 25°C;	MIL-STD-202, Method 215

All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
	distilled water + proylene glycol monomethyl ether + monoethanolamine at 63°C to 70°C	